

IPA65R280C6XKSA1

IPA65R280C6XKSA1 Information

	whyw.helsener2.com	 IPA65R280C6XKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 650V 13.8A TO220 TO-220-3 Full Pack For the pricing/inventory/lead time, please contact	
	For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPA65R280C6XKSA1 Specifications

Manufacturer Part Number	IPA65R280C6XKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	13.8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 440µA
Gate Charge (Qg) (Max) @ Vgs	45nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	950pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	32W (Tc)
Rds On (Max) @ Id, Vgs	280 mOhm @ 4.4A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220 Full Pack
Package / Case	TO-220-3 Full Pack
	Report errors?

IPA65R280C6XKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPA65R280C6XKSA1 Payment Methods



If you have any question about IPA65R280C6XKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com